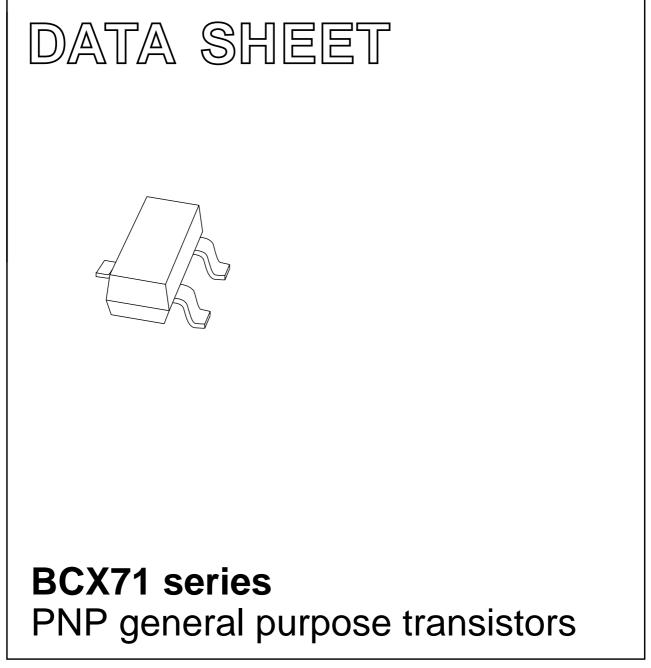
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 20 2004 Feb 16



FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 45 V)
- Low noise.

APPLICATIONS

- Low level, low noise, low frequency applications in hybrid circuits
- General purpose switching and amplification.

DESCRIPTION

PNP transistor in a plastic SOT23 package. NPN complements: BCX70 series.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾		
BCX71H	BH*		
BCX71J BJ*			
BCX71K	BK*		

Note

- 1. * = p : Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

ORDERING INFORMATION

TYPE		PACKAGE	
NUMBER NAME DESCRIPTION		DESCRIPTION	VERSION
BCX71H	_	plastic surface mounted package; 3 leads	SOT23
BCX71J			
BCX71K			

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	

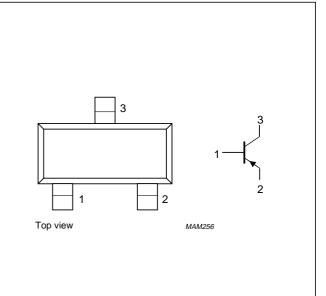


Fig.1 Simplified outline (SOT23) and symbol.

BCX71 series

BCX71 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-45	V
V _{CEO}	collector-emitter voltage	open base	-	-45	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current (DC)		-	-100	mA
I _{CM}	peak collector current		-	-200	mA
I _{BM}	peak base current		-	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

BCX71 series

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	I _E = 0; V _{CB} = -45 V	-	-	-20	nA
		$I_E = 0; V_{CB} = -45 \text{ V}; T_{amb} = 150 \text{ °C}$	-	_	-20	μA
I _{EBO}	emitter-base cut-off current	$I_{C} = 0; V_{EB} = -4 V$	-	_	-20	nA
h _{FE}	DC current gain	$I_{C} = -10 \ \mu A; \ V_{CE} = -5 \ V$				
	BCX71H		30	-	-	
	BCX71J		40	_	-	
	BCX71K		100	_	_	
	DC current gain	$I_{C} = -2 \text{ mA}; V_{CE} = -5 \text{ V}$				
	BCX71H		180	_	310	
	BCX71J		250	_	460	
	BCX71K		380	_	630	
	DC current gain	$I_{C} = -50 \text{ mA}; V_{CE} = -1 \text{ V}; \text{ note } 1$				
	BCX71H		80	_	_	
	BCX71J		100	_	_	
	BCX71K		110	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -10$ mA; $I_{\rm B} = -0.25$ mA	-60	_	-250	mV
		$I_{C} = -50 \text{ mA}; I_{B} = -1.25 \text{ mA}; \text{ note } 1$	-120	_	-550	mV
V _{BEsat}	base-emitter saturation	$I_{\rm C} = -10 \text{ mA}; I_{\rm B} = -0.25 \text{ mA}$	-600	_	-850	mV
	voltage	$I_{C} = -50 \text{ mA}; I_{B} = -1.25 \text{ mA}; \text{ note } 1$	-680	_	-1050	mV
V _{BE}	base-emitter voltage	$I_{C} = -2 \text{ mA}; V_{CE} = -5 \text{ V}$	-600	-650	-750	mV
		$I_{C} = -10 \ \mu A; \ V_{CE} = -5 \ V$	-	-550	-	mV
		$I_{C} = -50 \text{ mA}; V_{CE} = -1 \text{ V}; \text{ note } 1$	_	-720	_	mV
C _c	collector capacitance	$I_E = I_e = 0; V_{CB} = -10 V; f = 1 MHz$	_	4.5	_	pF
C _e	emitter capacitance	$I_{C} = I_{c} = 0; V_{EB} = -0.5 \text{ V}; f = 1 \text{ MHz}$	-	11	-	pF
f _T	transition frequency	$I_{C} = -10 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$	100	_	_	MHz
F	noise figure	$ I_C = -200 \ \mu \text{A}; \ \text{V}_{CE} = -5 \ \text{V}; \ \text{R}_S = 2 \ \text{k}\Omega; \\ f = 1 \ \text{kHz}; \ \text{B} = 200 \ \text{Hz} $	-	2	6	dB

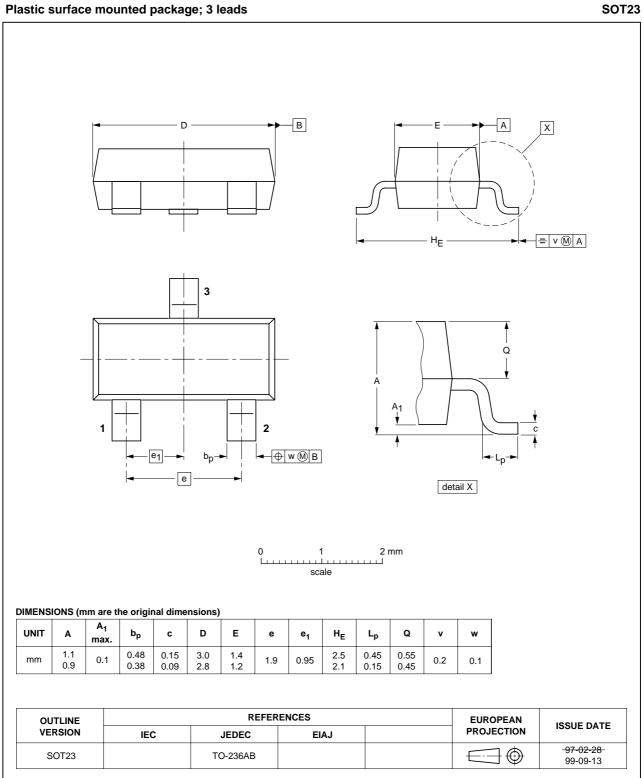
Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

BCX71 series

PNP general purpose transistors

PACKAGE OUTLINE



BCX71 series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products including circuits, standard cells, and/or software described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors – a worldwide company

Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2004

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

R75/04/pp7

Date of release: 2004 Feb 16

Document order number: 9397 750 12409

SCA76

Let's make things better.





Philips Semiconductors